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#### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

#### Applications of "[Embedded - Microcontrollers](#)"

##### Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	I²C, LINbus, SPI, TSI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I²S, LVD, POR, PWM, WDT
Number of I/O	54
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D - 16bit; D/A - 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl16z256vlh4">https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl16z256vlh4</a>

# Table of Contents

1 Ratings.....	4	3.6.2 CMP and 6-bit DAC electrical specifications.....	30
1.1 Thermal handling ratings.....	4	3.6.3 12-bit DAC electrical characteristics.....	33
1.2 Moisture handling ratings.....	4	3.7 Timers.....	36
1.3 ESD handling ratings.....	4	3.8 Communication interfaces.....	36
1.4 Voltage and current operating ratings.....	4	3.8.1 SPI switching specifications.....	36
2 General.....	5	3.8.2 Inter-Integrated Circuit Interface (I2C) timing.....	41
2.1 AC electrical characteristics.....	5	3.8.3 UART.....	42
2.2 Nonswitching electrical specifications.....	5	3.8.4 I2S/SAI switching specifications.....	42
2.2.1 Voltage and current operating requirements.....	6	3.9 Human-machine interfaces (HMI).....	46
2.2.2 LVD and POR operating requirements.....	6	3.9.1 TSI electrical specifications.....	46
2.2.3 Voltage and current operating behaviors.....	7	4 Dimensions.....	47
2.2.4 Power mode transition operating behaviors.....	8	4.1 Obtaining package dimensions.....	47
2.2.5 Power consumption operating behaviors.....	9	5 Pinout.....	47
2.2.6 EMC radiated emissions operating behaviors... 15		5.1 KL16 Signal Multiplexing and Pin Assignments.....	47
2.2.7 Designing with radiated emissions in mind.....	16	5.2 KL16 pinouts.....	50
2.2.8 Capacitance attributes.....	16	6 Ordering parts.....	52
2.3 Switching specifications.....	16	6.1 Determining valid orderable parts.....	52
2.3.1 Device clock specifications.....	16	7 Part identification.....	52
2.3.2 General switching specifications.....	17	7.1 Description.....	52
2.4 Thermal specifications.....	17	7.2 Format.....	53
2.4.1 Thermal operating requirements.....	17	7.3 Fields.....	53
2.4.2 Thermal attributes.....	17	7.4 Example.....	53
3 Peripheral operating requirements and behaviors.....	18	8 Terminology and guidelines.....	54
3.1 Core modules.....	18	8.1 Definition: Operating requirement.....	54
3.1.1 SWD electrics .....	18	8.2 Definition: Operating behavior.....	54
3.2 System modules.....	20	8.3 Definition: Attribute.....	54
3.3 Clock modules.....	20	8.4 Definition: Rating.....	55
3.3.1 MCG specifications.....	20	8.5 Result of exceeding a rating.....	55
3.3.2 Oscillator electrical specifications.....	22	8.6 Relationship between ratings and operating	
3.4 Memories and memory interfaces.....	24	requirements.....	55
3.4.1 Flash electrical specifications.....	24	8.7 Guidelines for ratings and operating requirements.....	56
3.5 Security and integrity modules.....	25	8.8 Definition: Typical value.....	56
3.6 Analog.....	25	8.9 Typical value conditions.....	57
3.6.1 ADC electrical specifications.....	26	9 Revision history.....	58

**Table 6. V<sub>DD</sub> supply LVD and POR operating requirements (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>LVW1H</sub>	• Level 1 falling (LVWV = 00)	2.62	2.70	2.78	V	
V <sub>LVW2H</sub>	• Level 2 falling (LVWV = 01)	2.72	2.80	2.88	V	
V <sub>LVW3H</sub>	• Level 3 falling (LVWV = 10)	2.82	2.90	2.98	V	
V <sub>LVW4H</sub>	• Level 4 falling (LVWV = 11)	2.92	3.00	3.08	V	
V <sub>HYSH</sub>	Low-voltage inhibit reset/recover hysteresis — high range	—	±60	—	mV	—
V <sub>LVDL</sub>	Falling low-voltage detect threshold — low range (LVDV=00)	1.54	1.60	1.66	V	—
	Low-voltage warning thresholds — low range					1
V <sub>LVW1L</sub>	• Level 1 falling (LVWV = 00)	1.74	1.80	1.86	V	
V <sub>LVW2L</sub>	• Level 2 falling (LVWV = 01)	1.84	1.90	1.96	V	
V <sub>LVW3L</sub>	• Level 3 falling (LVWV = 10)	1.94	2.00	2.06	V	
V <sub>LVW4L</sub>	• Level 4 falling (LVWV = 11)	2.04	2.10	2.16	V	
V <sub>HYSL</sub>	Low-voltage inhibit reset/recover hysteresis — low range	—	±40	—	mV	—
V <sub>BG</sub>	Bandgap voltage reference	0.97	1.00	1.03	V	—
t <sub>LPO</sub>	Internal low power oscillator period — factory trimmed	900	1000	1100	μs	—

1. Rising thresholds are falling threshold + hysteresis voltage

### 2.2.3 Voltage and current operating behaviors

**Table 7. Voltage and current operating behaviors**

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>OH</sub>	Output high voltage — Normal drive pad (except RESET_b)	V <sub>DD</sub> – 0.5	—	V	1, 2
	• 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V, I <sub>OH</sub> = -5 mA	V <sub>DD</sub> – 0.5	—	V	
	• 1.71 V ≤ V <sub>DD</sub> ≤ 2.7 V, I <sub>OH</sub> = -2.5 mA				
V <sub>OH</sub>	Output high voltage — High drive pad (except RESET_b)	V <sub>DD</sub> – 0.5	—	V	1, 2
	• 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V, I <sub>OH</sub> = -20 mA	V <sub>DD</sub> – 0.5	—	V	
	• 1.71 V ≤ V <sub>DD</sub> ≤ 2.7 V, I <sub>OH</sub> = -10 mA				
I <sub>OHT</sub>	Output high current total for all ports	—	100	mA	
V <sub>OL</sub>	Output low voltage — Normal drive pad	—	0.5	V	1
	• 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V, I <sub>OL</sub> = 5 mA	—	0.5	V	
	• 1.71 V ≤ V <sub>DD</sub> ≤ 2.7 V, I <sub>OL</sub> = 2.5 mA				

Table continues on the next page...

**Table 7. Voltage and current operating behaviors (continued)**

Symbol	Description	Min.	Max.	Unit	Notes
$V_{OL}$	Output low voltage — High drive pad • $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ , $I_{OL} = 20 \text{ mA}$ • $1.71 \text{ V} \leq V_{DD} \leq 2.7 \text{ V}$ , $I_{OL} = 10 \text{ mA}$	—	0.5	V	1
$I_{OLT}$	Output low current total for all ports	—	100	mA	
$I_{IN}$	Input leakage current (per pin) for full temperature range	—	1	$\mu\text{A}$	3
$I_{IN}$	Input leakage current (per pin) at $25^\circ\text{C}$	—	0.025	$\mu\text{A}$	3
$I_{IN}$	Input leakage current (total all pins) for full temperature range	—		$\mu\text{A}$	3
$I_{OZ}$	Hi-Z (off-state) leakage current (per pin)	—	1	$\mu\text{A}$	
$R_{PU}$	Internal pullup resistors	20	50	k $\Omega$	4

- PTB0, PTB1, PTD6, and PTD7 I/O have both high drive and normal drive capability selected by the associated PTx\_PCRn[DSE] control bit. All other GPIOs are normal drive only.
- The reset pin only contains an active pull down device when configured as the RESET signal or as a GPIO. When configured as a GPIO output, it acts as a pseudo open drain output.
- Measured at  $V_{DD} = 3.6 \text{ V}$
- Measured at  $V_{DD}$  supply voltage =  $V_{DD}$  min and  $V_{in} = V_{SS}$

## 2.2.4 Power mode transition operating behaviors

All specifications except  $t_{POR}$  and VLLSx $\rightarrow$ RUN recovery times in the following table assume this clock configuration:

- CPU and system clocks = 48 MHz
- Bus and flash clock = 24 MHz
- FEI clock mode

POR and VLLSx $\rightarrow$ RUN recovery use FEI clock mode at the default CPU and system frequency of 21 MHz, and a bus and flash clock frequency of 10.5 MHz.

**Table 8. Power mode transition operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{POR}$	After a POR event, amount of time from the point $V_{DD}$ reaches 1.8 V to execution of the first instruction across the operating temperature range of the chip.	—	—	300	$\mu\text{s}$	1
	• VLLS0 $\rightarrow$ RUN	—	113	124	$\mu\text{s}$	

Table continues on the next page...

**Table 8. Power mode transition operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	• VLLS1 → RUN	—	112	124	μs	
	• VLLS3 → RUN	—	53	60	μs	
	• LLS → RUN	—	4.5	5.0	μs	
	• VLPS → RUN	—	4.5	5.0	μs	
	• STOP → RUN	—	4.5	5.0	μs	

1. Normal boot (FTFA\_FOPT[LPBOOT]=11).

## 2.2.5 Power consumption operating behaviors

The maximum values stated in the following table represent characterized results equivalent to the mean plus three times the standard deviation (mean + 3 sigma).

**Table 9. Power consumption operating behaviors**

Symbol	Description	Typ.	Max	Unit	Note
I <sub>DDA</sub>	Analog supply current	—	—	See note	mA
I <sub>DD_RUNCO_CM</sub>	Run mode current in compute operation - 48 MHz core / 24 MHz flash/ bus disabled, LPTMR running using 4 MHz internal reference clock, CoreMark® benchmark code executing from flash, at 3.0 V	—	6.7	—	mA
I <sub>DD_RUNCO</sub>	Run mode current in compute operation - 48 MHz core / 24 MHz flash / bus clock disabled, code of while(1) loop executing from flash, at 3.0 V	—	4.5	5.1	mA
I <sub>DD_RUN</sub>	Run mode current - 48 MHz core / 24 MHz bus and flash, all peripheral clocks disabled, code executing from flash	at 1.8 V	5.6	6.3	mA
		at 3.0 V	5.4	6.0	mA
I <sub>DD_RUN</sub>	Run mode current - 48 MHz core / 24 MHz bus and flash, all peripheral clocks enabled, code executing from flash, at 1.8 V	—	6.9	7.3	mA
	Run mode current - 48 MHz core / 24 MHz bus and flash, all peripheral clocks enabled, code executing from flash, at 3.0 V	at 25 °C	6.9	7.1	mA
		at 125 °C	7.3	7.6	mA

Table continues on the next page...

**Table 10. Low power mode peripheral adders — typical value (continued)**

Symbol	Description	Temperature (°C)						Unit
		-40	25	50	70	85	105	
I <sub>BG</sub>	Bandgap adder when BGEN bit is set and device is placed in VLPx, LLS, or VLLSx mode.	45	45	45	45	45	45	µA
I <sub>ADC</sub>	ADC peripheral adder combining the measured values at V <sub>DD</sub> and V <sub>DDA</sub> by placing the device in STOP or VLPS mode. ADC is configured for low power mode using the internal clock and continuous conversions.	366	366	366	366	366	366	µA

### 2.2.5.1 Diagram: Typical IDD\_RUN operating behavior

The following data was measured under these conditions:

- MCG in FBE for run mode, and BLPE for VLPR mode
- No GPIOs toggled
- Code execution from flash with cache enabled
- For the ALLOFF curve, all peripheral clocks are disabled except FTFA

1. The frequency limitations in VLPR and VLPS modes here override any frequency specification listed in the timing specification for any other module. These same frequency limits apply to VLPS, whether VLPS was entered from RUN or from VLPR.
2. The LPTMR can be clocked at this speed in VLPR or VLPS only when the source is an external pin.

### 2.3.2 General switching specifications

These general-purpose specifications apply to all signals configured for GPIO and UART signals.

**Table 14. General switching specifications**

Description	Min.	Max.	Unit	Notes
GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	—	Bus clock cycles	1
External RESET and NMI pin interrupt pulse width — Asynchronous path	100	—	ns	2
GPIO pin interrupt pulse width — Asynchronous path	16	—	ns	2
Port rise and fall time	—	36	ns	3

1. The greater synchronous and asynchronous timing must be met.
2. This is the shortest pulse that is guaranteed to be recognized.
3. 75 pF load

### 2.4 Thermal specifications

#### 2.4.1 Thermal operating requirements

**Table 15. Thermal operating requirements**

Symbol	Description	Min.	Max.	Unit
T <sub>J</sub>	Die junction temperature	-40	125	°C
T <sub>A</sub>	Ambient temperature	-40	105	°C

**Table 18. MCG specifications (continued)**

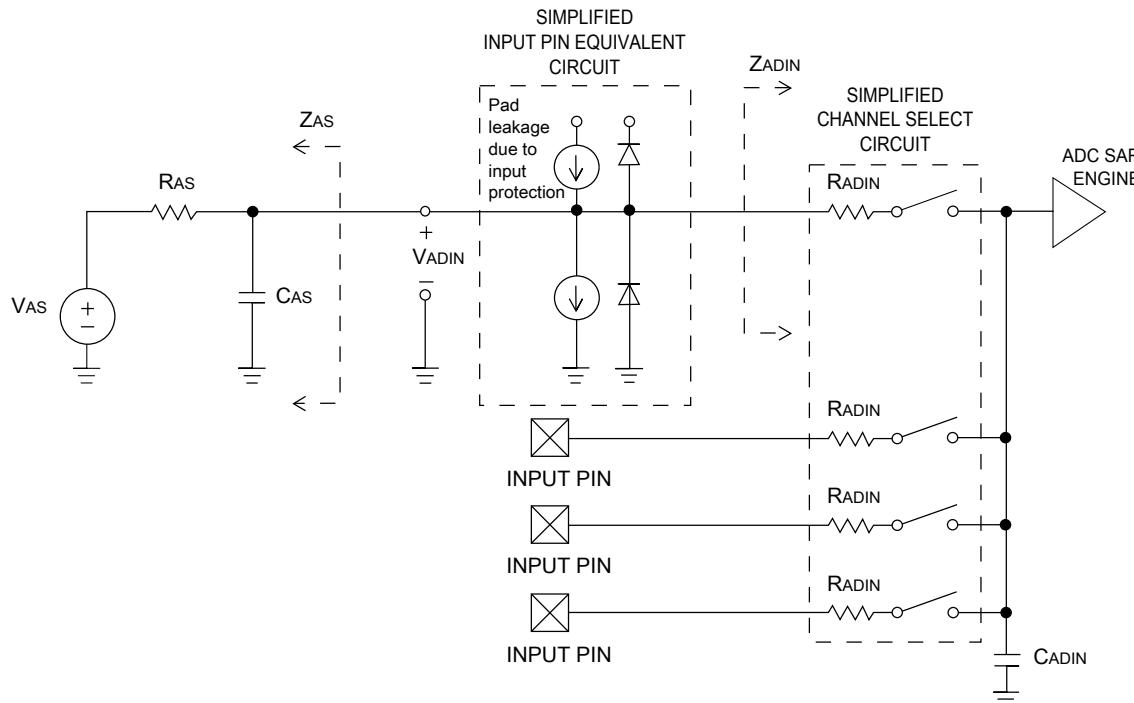
Symbol	Description	Min.	Typ.	Max.	Unit	Notes
		$732 \times f_{\text{fll\_ref}}$				
		—	47.97	—	MHz	
		$1464 \times f_{\text{fll\_ref}}$				
$J_{\text{cyc\_fll}}$	FLL period jitter • $f_{\text{VCO}} = 48 \text{ MHz}$	—	180	—	ps	7
$t_{\text{fll\_acquire}}$	FLL target frequency acquisition time	—	—	1	ms	8
PLL						
$f_{\text{vco}}$	VCO operating frequency	48.0	—	100	MHz	
$I_{\text{pll}}$	PLL operating current • PLL at 96 MHz ( $f_{\text{osc\_hi\_1}} = 8 \text{ MHz}$ , $f_{\text{pll\_ref}} = 2 \text{ MHz}$ , VDIV multiplier = 48)	—	1060	—	$\mu\text{A}$	9
$I_{\text{pll}}$	PLL operating current • PLL at 48 MHz ( $f_{\text{osc\_hi\_1}} = 8 \text{ MHz}$ , $f_{\text{pll\_ref}} = 2 \text{ MHz}$ , VDIV multiplier = 24)	—	600	—	$\mu\text{A}$	9
$f_{\text{pll\_ref}}$	PLL reference frequency range	2.0	—	4.0	MHz	
$J_{\text{cyc\_pll}}$	PLL period jitter (RMS)	—	120	—	ps	10
	• $f_{\text{VCO}} = 48 \text{ MHz}$	—	—	—	ps	
$J_{\text{acc\_pll}}$	PLL accumulated jitter over 1 $\mu\text{s}$ (RMS)	—	1350	—	ps	10
	• $f_{\text{VCO}} = 48 \text{ MHz}$	—	600	—	ps	
$D_{\text{lock}}$	Lock entry frequency tolerance	$\pm 1.49$	—	$\pm 2.98$	%	
$D_{\text{unl}}$	Lock exit frequency tolerance	$\pm 4.47$	—	$\pm 5.97$	%	
$t_{\text{pll\_lock}}$	Lock detector detection time	—	—	$150 \times 10^{-6} + 1075(1/f_{\text{pll\_ref}})$	s	11

1. This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).
2. The deviation is relative to the factory trimmed frequency at nominal  $V_{\text{DD}}$  and  $25^\circ\text{C}$ ,  $f_{\text{ints\_ft}}$ .
3. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 0.
4. The resulting system clock frequencies must not exceed their maximum specified values. The DCO frequency deviation ( $\Delta f_{\text{dco\_t}}$ ) over voltage and temperature must be considered.
5. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 1.
6. The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
7. This specification is based on standard deviation (RMS) of period or frequency.
8. This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
9. Excludes any oscillator currents that are also consuming power while PLL is in operation.
10. This specification was obtained using a Freescale developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary.
11. This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

**Table 25. 16-bit ADC operating conditions (continued)**

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
C <sub>rate</sub>	ADC conversion rate	16-bit mode No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	37.037	—	461.467	Ksps	5

1. Typical values assume V<sub>DDA</sub> = 3.0 V, Temp = 25 °C, f<sub>ADCK</sub> = 1.0 MHz, unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had < 8 Ω analog source resistance. The R<sub>AS</sub>/C<sub>CAS</sub> time constant should be kept to < 1 ns.
4. To use the maximum ADC conversion clock frequency, CFG2[ADHSC] must be set and CFG1[ADLPC] must be clear.
5. For guidelines and examples of conversion rate calculation, download the [ADC calculator tool](#).

**Figure 7. ADC input impedance equivalency diagram**

### 3.6.1.2 16-bit ADC electrical characteristics

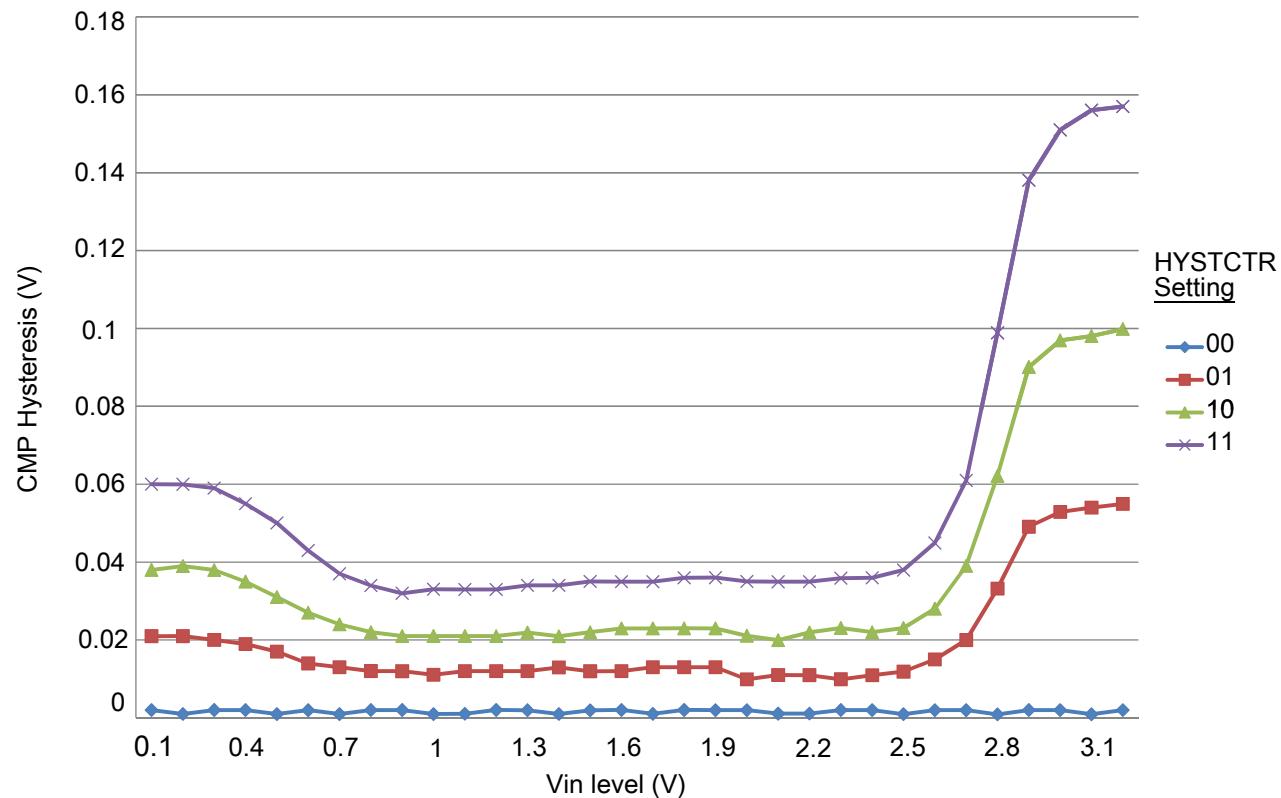


Figure 11. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 1)

### 3.6.3 12-bit DAC electrical characteristics

#### 3.6.3.1 12-bit DAC operating requirements

Table 28. 12-bit DAC operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
$V_{DDA}$	Supply voltage	1.71	3.6	V	
$V_{DACP}$	Reference voltage	1.13	3.6	V	<a href="#">1</a>
$C_L$	Output load capacitance	—	100	pF	<a href="#">2</a>
$I_L$	Output load current	—	1	mA	

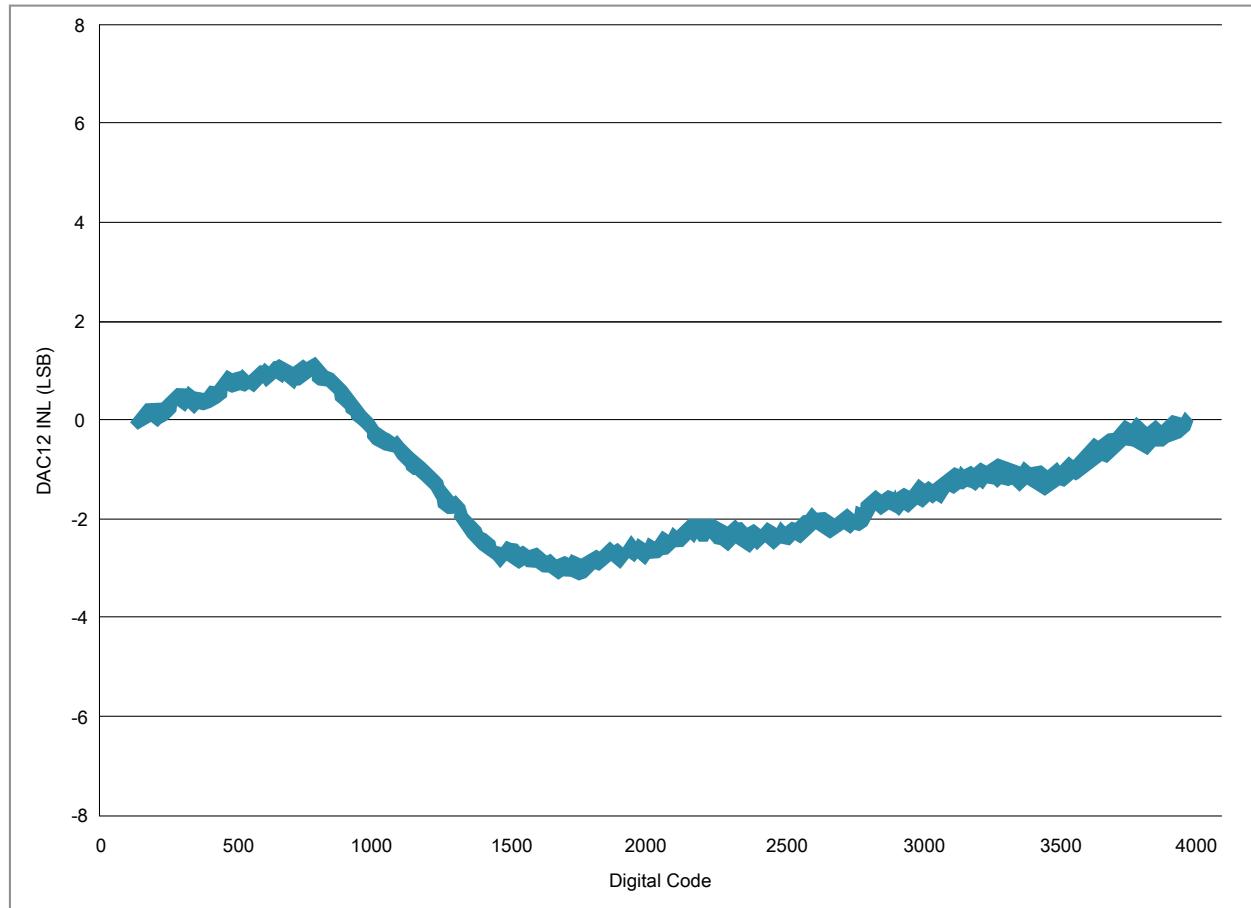
1. The DAC reference can be selected to be  $V_{DDA}$  or  $V_{REFH}$ .
2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC.

### 3.6.3.2 12-bit DAC operating behaviors

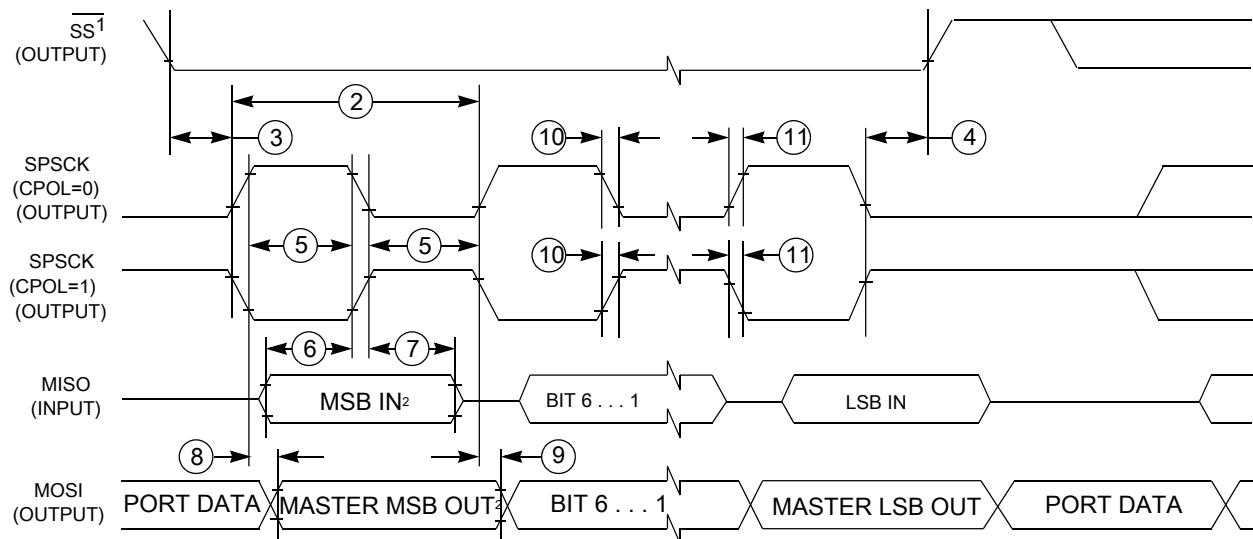
**Table 29. 12-bit DAC operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$I_{DDA\_DACL_P}$	Supply current — low-power mode	—	—	250	µA	
$I_{DDA\_DACH_P}$	Supply current — high-speed mode	—	—	900	µA	
$t_{DACLP}$	Full-scale settling time (0x080 to 0xF7F) — low-power mode	—	100	200	µs	1
$t_{DACHP}$	Full-scale settling time (0x080 to 0xF7F) — high-power mode	—	15	30	µs	1
$t_{CCDACLP}$	Code-to-code settling time (0xBF8 to 0xC08) — low-power mode and high-speed mode	—	0.7	1	µs	1
$V_{dacoutl}$	DAC output voltage range low — high-speed mode, no load, DAC set to 0x000	—	—	100	mV	
$V_{dacouth}$	DAC output voltage range high — high-speed mode, no load, DAC set to 0xFFFF	$V_{DACR} - 100$	—	$V_{DACR}$	mV	
INL	Integral non-linearity error — high speed mode	—	—	±8	LSB	2
DNL	Differential non-linearity error — $V_{DACR} > 2$ V	—	—	±1	LSB	3
DNL	Differential non-linearity error — $V_{DACR} = V_{REF\_OUT}$	—	—	±1	LSB	4
$V_{OFFSET}$	Offset error	—	±0.4	±0.8	%FSR	5
$E_G$	Gain error	—	±0.1	±0.6	%FSR	5
PSRR	Power supply rejection ratio, $V_{DDA} \geq 2.4$ V	60	—	90	dB	
$T_{CO}$	Temperature coefficient offset voltage	—	3.7	—	µV/C	6
$T_{GE}$	Temperature coefficient gain error	—	0.000421	—	%FSR/C	
$R_{op}$	Output resistance (load = 3 kΩ)	—	—	250	Ω	
SR	Slew rate -80h → F7Fh → 80h <ul style="list-style-type: none"> <li>• High power (<math>SP_{HP}</math>)</li> <li>• Low power (<math>SP_{LP}</math>)</li> </ul>	1.2 0.05	1.7 0.12	— —	V/µs	
BW	3dB bandwidth <ul style="list-style-type: none"> <li>• High power (<math>SP_{HP}</math>)</li> <li>• Low power (<math>SP_{LP}</math>)</li> </ul>	550 40	— —	— —	kHz	

- Settling within ±1 LSB
- The INL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV
- The DNL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV
- The DNL is measured for 0 + 100 mV to  $V_{DACR} - 100$  mV with  $V_{DDA} > 2.4$  V
- Calculated by a best fit curve from  $V_{SS} + 100$  mV to  $V_{DACR} - 100$  mV
- $V_{DDA} = 3.0$  V, reference select set for  $V_{DDA}$  ( $DACx\_CO:DACRFS = 1$ ), high power mode ( $DACx\_C0:LPEN = 0$ ), DAC set to 0x800, temperature range is across the full range of the device



**Figure 12. Typical INL error vs. digital code**



**Figure 15. SPI master mode timing (CPHA = 1)**

**Table 32. SPI slave mode timing on slew rate disabled pads**

Num.	Symbol	Description	Min.	Max.	Unit	Note
1	$f_{op}$	Frequency of operation	0	$f_{periph}/4$	Hz	<a href="#">1</a>
2	$t_{SPSCK}$	SPSCK period	$4 \times t_{periph}$	—	ns	<a href="#">2</a>
3	$t_{Lead}$	Enable lead time	1	—	$t_{periph}$	—
4	$t_{Lag}$	Enable lag time	1	—	$t_{periph}$	—
5	$t_{WSPSCK}$	Clock (SPSCK) high or low time	$t_{periph} - 30$	—	ns	—
6	$t_{SU}$	Data setup time (inputs)	2.5	—	ns	—
7	$t_{HI}$	Data hold time (inputs)	3.5	—	ns	—
8	$t_a$	Slave access time	—	$t_{periph}$	ns	<a href="#">3</a>
9	$t_{dis}$	Slave MISO disable time	—	$t_{periph}$	ns	<a href="#">4</a>
10	$t_v$	Data valid (after SPSCK edge)	—	31	ns	—
11	$t_{HO}$	Data hold time (outputs)	0	—	ns	—
12	$t_{RI}$	Rise time input	—	$t_{periph} - 25$	ns	—
	$t_{FI}$	Fall time input	—	—	ns	—
13	$t_{RO}$	Rise time output	—	25	ns	—
	$t_{FO}$	Fall time output	—	—	ns	—

- For SPI0  $f_{periph}$  is the bus clock ( $f_{BUS}$ ). For SPI1  $f_{periph}$  is the system clock ( $f_{SYS}$ ).
- $t_{periph} = 1/f_{periph}$
- Time to data active from high-impedance state
- Hold time to high-impedance state

**Table 33. SPI slave mode timing on slew rate enabled pads**

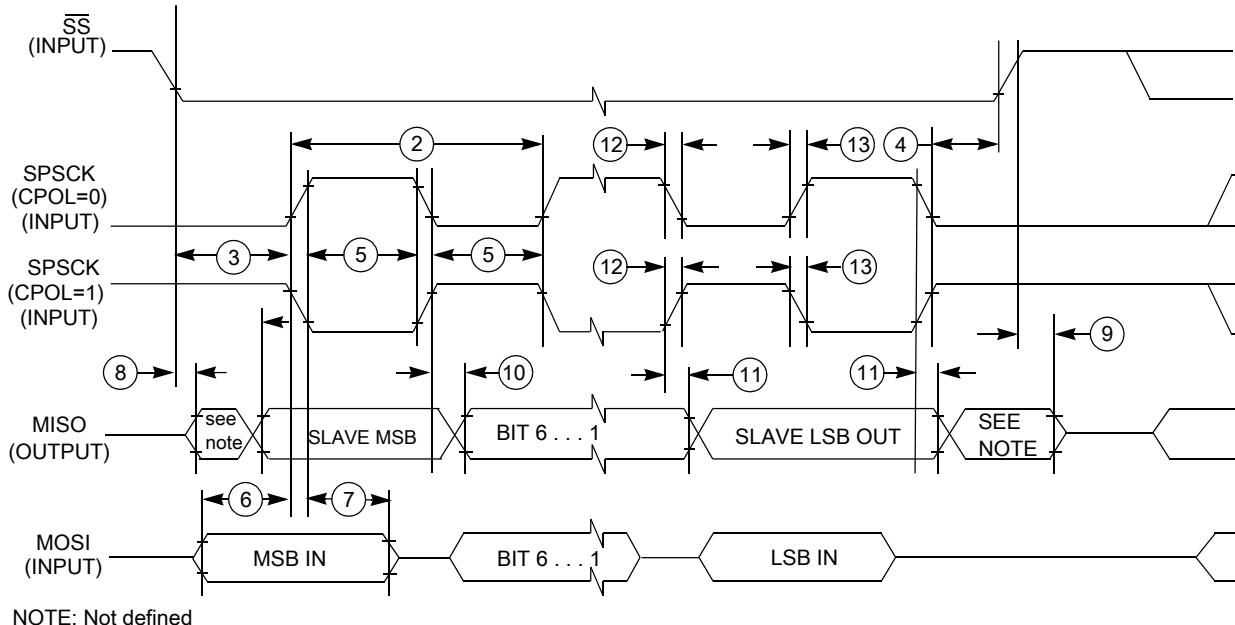
Num.	Symbol	Description	Min.	Max.	Unit	Note
1	$f_{op}$	Frequency of operation	0	$f_{periph}/4$	Hz	1
2	$t_{SPSCK}$	SPSCK period	$4 \times t_{periph}$	—	ns	2
3	$t_{Lead}$	Enable lead time	1	—	$t_{periph}$	—
4	$t_{Lag}$	Enable lag time	1	—	$t_{periph}$	—
5	$t_{WSPSCK}$	Clock (SPSCK) high or low time	$t_{periph} - 30$	—	ns	—
6	$t_{SU}$	Data setup time (inputs)	2	—	ns	—
7	$t_{HI}$	Data hold time (inputs)	7	—	ns	—
8	$t_a$	Slave access time	—	$t_{periph}$	ns	3
9	$t_{dis}$	Slave MISO disable time	—	$t_{periph}$	ns	4
10	$t_v$	Data valid (after SPSCK edge)	—	122	ns	—
11	$t_{HO}$	Data hold time (outputs)	0	—	ns	—
12	$t_{RI}$	Rise time input	—	$t_{periph} - 25$	ns	—
	$t_{FI}$	Fall time input				
13	$t_{RO}$	Rise time output	—	36	ns	—
	$t_{FO}$	Fall time output				

1. For SPI0  $f_{periph}$  is the bus clock ( $f_{BUS}$ ). For SPI1  $f_{periph}$  is the system clock ( $f_{SYS}$ ).

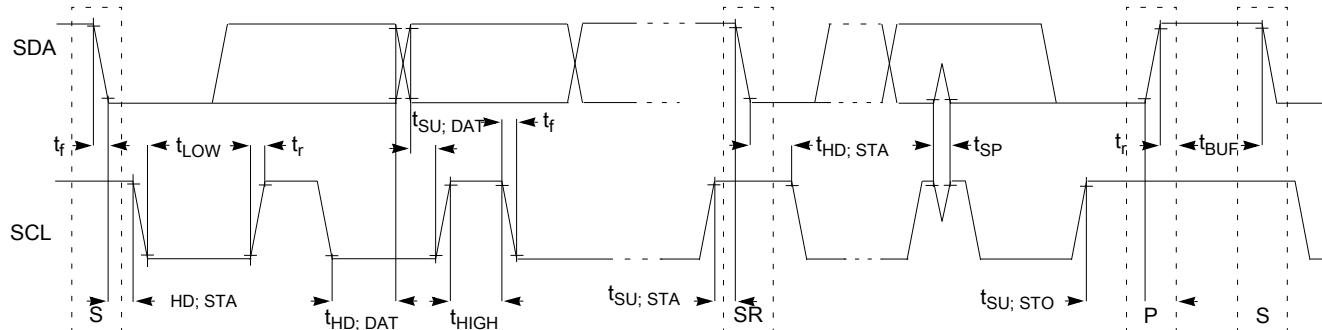
2.  $t_{periph} = 1/f_{periph}$

3. Time to data active from high-impedance state

4. Hold time to high-impedance state

**Figure 16. SPI slave mode timing (CPHA = 0)**

2. The master mode I<sup>2</sup>C deasserts ACK of an address byte simultaneously with the falling edge of SCL. If no slaves acknowledge this address byte, then a negative hold time can result, depending on the edge rates of the SDA and SCL lines.
3. The maximum tHD; DAT must be met only if the device does not stretch the LOW period (tLOW) of the SCL signal.
4. Input signal Slew = 10 ns and Output Load = 50 pF
5. Set-up time in slave-transmitter mode is 1 IPBus clock period, if the TX FIFO is empty.
6. A Fast mode I<sup>2</sup>C bus device can be used in a Standard mode I<sup>2</sup>C bus system, but the requirement  $t_{SU; DAT} \geq 250$  ns must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, then it must output the next data bit to the SDA line  $t_{rmax} + t_{SU; DAT} = 1000 + 250 = 1250$  ns (according to the Standard mode I<sup>2</sup>C bus specification) before the SCL line is released.
7.  $C_b$  = total capacitance of the one bus line in pF.



**Figure 18. Timing definition for fast and standard mode devices on the I<sup>2</sup>C bus**

### 3.8.3 UART

See [General switching specifications](#).

### 3.8.4 I2S/SAI switching specifications

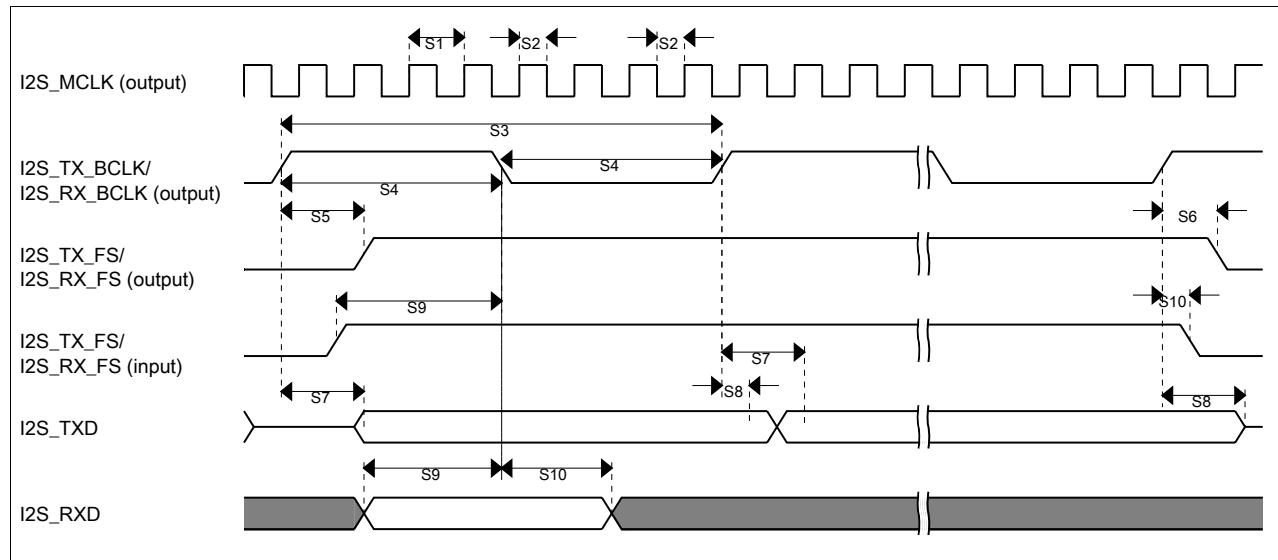
This section provides the AC timing for the I2S/SAI module in master mode (clocks are driven) and slave mode (clocks are input). All timing is given for noninverted serial clock polarity (TCR2[BCP] is 0, RCR2[BCP] is 0) and a noninverted frame sync (TCR4[FSP] is 0, RCR4[FSP] is 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the bit clock signal (BCLK) and/or the frame sync (FS) signal shown in the following figures.

### 3.8.4.1 Normal Run, Wait and Stop mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in Normal Run, Wait and Stop modes.

**Table 35. I2S/SAI master mode timing**

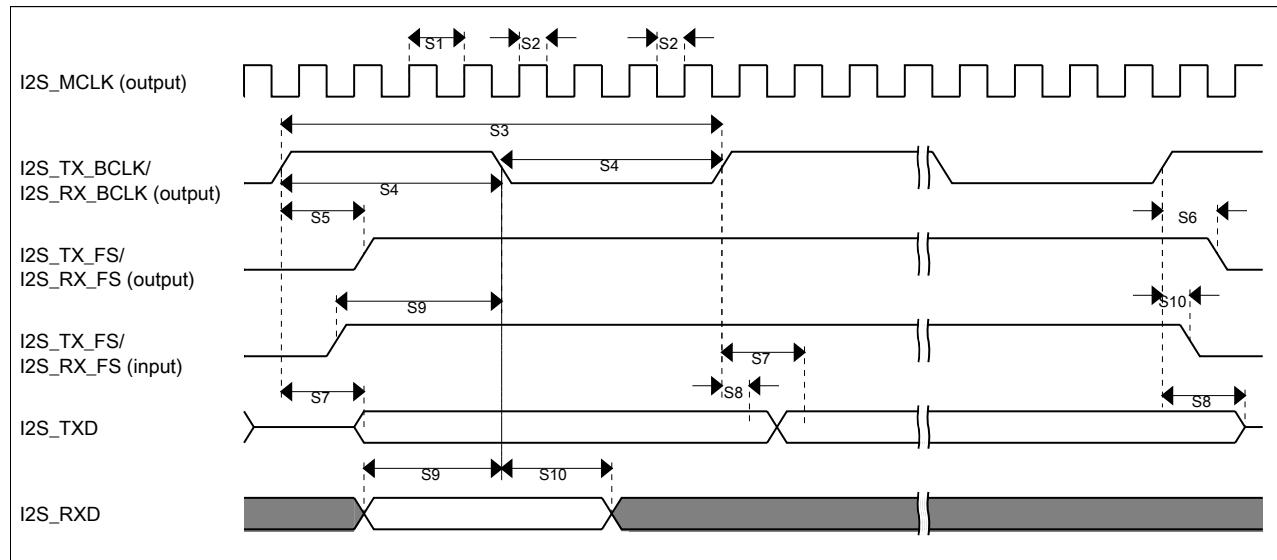
Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	40	—	ns
S2	I2S_MCLK (as an input) pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	80	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	15.5	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	19	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	26	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns



**Figure 19. I2S/SAI timing — master modes**

**Table 37. I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes (full voltage range)**

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	62.5	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	250	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	45	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	45	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	75	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns



**Figure 21. I2S/SAI timing — master modes**

**Table 38. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range)**

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	250	—	ns

Table continues on the next page...

**Pinout**

64 BGA	64 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
—	3	VDD	VDD	VDD							
C4	4	VSS	VSS	VSS							
E1	5	PTE16	ADC0_DP1/ ADC0_SE1	ADC0_DP1/ ADC0_SE1	PTE16	SPI0_PCS0	UART2_TX	TPM_CLKIN0			
D1	6	PTE17	ADC0_DM1/ ADC0_SE5a	ADC0_DM1/ ADC0_SE5a	PTE17	SPI0_SCK	UART2_RX	TPM_CLKIN1		LPTMR0_ ALT3	
E2	7	PTE18	ADC0_DP2/ ADC0_SE2	ADC0_DP2/ ADC0_SE2	PTE18	SPI0_MOSI		I2C0_SDA	SPI0_MISO		
D2	8	PTE19	ADC0_DM2/ ADC0_SE6a	ADC0_DM2/ ADC0_SE6a	PTE19	SPI0_MISO		I2C0_SCL	SPI0_MOSI		
G1	9	PTE20	ADC0_DP0/ ADC0_SE0	ADC0_DP0/ ADC0_SE0	PTE20		TPM1_CH0	UART0_TX			
F1	10	PTE21	ADC0_DM0/ ADC0_SE4a	ADC0_DM0/ ADC0_SE4a	PTE21		TPM1_CH1	UART0_RX			
G2	11	PTE22	ADC0_DP3/ ADC0_SE3	ADC0_DP3/ ADC0_SE3	PTE22		TPM2_CH0	UART2_TX			
F2	12	PTE23	ADC0_DM3/ ADC0_SE7a	ADC0_DM3/ ADC0_SE7a	PTE23		TPM2_CH1	UART2_RX			
F4	13	VDDA	VDDA	VDDA							
G4	14	VREFH	VREFH	VREFH							
G3	15	VREFL	VREFL	VREFL							
F3	16	VSSA	VSSA	VSSA							
H1	17	PTE29	CMP0_IN5/ ADC0_SE4b	CMP0_IN5/ ADC0_SE4b	PTE29		TPM0_CH2	TPM_CLKIN0			
H2	18	PTE30	DAC0_OUT/ ADC0_SE23/ CMP0_IN4	DAC0_OUT/ ADC0_SE23/ CMP0_IN4	PTE30		TPM0_CH3	TPM_CLKIN1			
H3	19	PTE31	DISABLED		PTE31		TPM0_CH4				
H4	20	PTE24	DISABLED		PTE24		TPM0_CH0		I2C0_SCL		
H5	21	PTE25	DISABLED		PTE25		TPM0_CH1		I2C0_SDA		
D3	22	PTA0	SWD_CLK	TSI0_CH1	PTA0		TPM0_CH5				SWD_CLK
D4	23	PTA1	DISABLED	TSI0_CH2	PTA1	UART0_RX	TPM2_CH0				
E5	24	PTA2	DISABLED	TSI0_CH3	PTA2	UART0_TX	TPM2_CH1				
D5	25	PTA3	SWD_DIO	TSI0_CH4	PTA3	I2C1_SCL	TPM0_CH0				SWD_DIO
G5	26	PTA4	NMI_b	TSI0_CH5	PTA4	I2C1_SDA	TPM0_CH1				NMI_b
F5	27	PTA5	DISABLED		PTA5		TPM0_CH2			I2S0_TX_ BCLK	
H6	28	PTA12	DISABLED		PTA12		TPM1_CH0			I2S0_TxD0	
G6	29	PTA13	DISABLED		PTA13		TPM1_CH1			I2S0_TX_FS	
G7	30	VDD	VDD	VDD							
H7	31	VSS	VSS	VSS							
H8	32	PTA18	EXTAL0	EXTAL0	PTA18		UART1_RX	TPM_CLKIN0			

## 7.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

## 7.2 Format

Part numbers for this device have the following format:

Q KL## A FFF R T PP CC N

## 7.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

**Table 40. Part number fields descriptions**

Field	Description	Values
Q	Qualification status	<ul style="list-style-type: none"> <li>M = Fully qualified, general market flow</li> <li>P = Prequalification</li> </ul>
KL##	Kinetis family	<ul style="list-style-type: none"> <li>KL16</li> </ul>
A	Key attribute	<ul style="list-style-type: none"> <li>Z = Cortex-M0+</li> </ul>
FFF	Program flash memory size	<ul style="list-style-type: none"> <li>256 = 256 KB</li> </ul>
R	Silicon revision	<ul style="list-style-type: none"> <li>(Blank) = Main</li> <li>A = Revision after main</li> </ul>
T	Temperature range (°C)	<ul style="list-style-type: none"> <li>V = -40 to 105</li> </ul>
PP	Package identifier	<ul style="list-style-type: none"> <li>LH = 64 LQFP (10 mm x 10 mm)</li> <li>MP = 64 MAPBGA (5 mm x 5 mm)</li> </ul>
CC	Maximum CPU frequency (MHz)	<ul style="list-style-type: none"> <li>4 = 48 MHz</li> </ul>
N	Packaging type	<ul style="list-style-type: none"> <li>R = Tape and reel</li> </ul>

## 7.4 Example

This is an example part number:

MKL16Z256VLH4

## 8 Terminology and guidelines

### 8.1 Definition: Operating requirement

An *operating requirement* is a specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip.

#### 8.1.1 Example

This is an example of an operating requirement:

Symbol	Description	Min.	Max.	Unit
V <sub>DD</sub>	1.0 V core supply voltage	0.9	1.1	V

### 8.2 Definition: Operating behavior

Unless otherwise specified, an *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

### 8.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

#### 8.3.1 Example

This is an example of an attribute:

Symbol	Description	Min.	Max.	Unit
CIN_D	Input capacitance: digital pins	—	7	pF

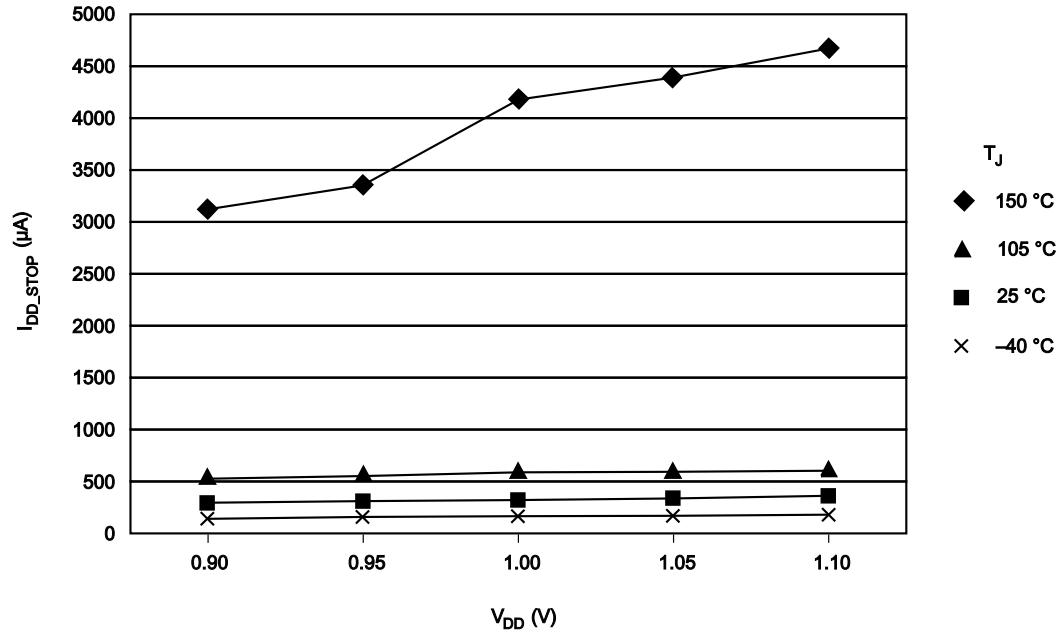
### 8.8.1 Example 1

This is an example of an operating behavior that includes a typical value:

Symbol	Description	Min.	Typ.	Max.	Unit
$I_{WP}$	Digital I/O weak pullup/pulldown current	10	70	130	μA

### 8.8.2 Example 2

This is an example of a chart that shows typical values for various voltage and temperature conditions:



## 8.9 Typical value conditions

Typical values assume you meet the following conditions (or other conditions as specified):